

# Instruction for Preparing Camera-Ready Abstracts for 2011 Intern. Workshop on Dielectric Thin Films for Future Electron Devices: Science and Technology (January 20-21, 2011)

Seiichi Miyazaki and Shin-ichi Takagi\*

Graduate School of Advanced Sciences of Matter, Hiroshima University, 1-3-1 Kagamiyama, Higashi-Hiroshima 739-8530, Japan

\*University of Tokyo, 7-3-1 Hongo, Bunkyo-ku, Tokyo 113-8656, Japan

TEL&FAX: +81-29-?????&+81-29-????, E-mail: IWDTF@????

## 1 Introduction

This set of instructions is given in the style and format to be used by authors preparing camera-ready abstracts for the Intern. Workshop on Dielectric Thin Films for Future Electron devices: Science and Technology 2011 (IWDTF2011). Papers to be presented at the Workshop will be selected by the Program Committee on the basis of the content from submitted abstracts. The abstracts should clearly and concisely state the specific results of the work and its originality. The abstracts of accepted papers will be printed as received and bound in the Extended Abstracts for the Workshop. All the authors of invited papers and contributed papers are expected to carefully follow the instructions.

## 2 General Instructions

The submitted abstracts must be in English, camera-ready in two pages including all figures and tables. The body of the abstracts must prepare to fit within an area of 17.0cm x 24.7cm in A4 size (or 8.5" x 11" :US letter size) white bond paper. For A4 size papers, set top and bottom margins to 25mm and left and right margins are to be 20mm. The first page of abstracts should be headed by the title, author(s), affiliation(s), address(es), contact author's phone number, fax number and e-mail address. The title should be written with bold letters and use capital letters for the initial letter of each word except articles, prepositions and conjunctions. Place a blank line between the title and author name(s), and between the author address(es) and the main text. The main text of the abstract must be single-spaced throughout in the two columns with full justification. Set the column separation to 5mm. A blank line is to be placed between the sections

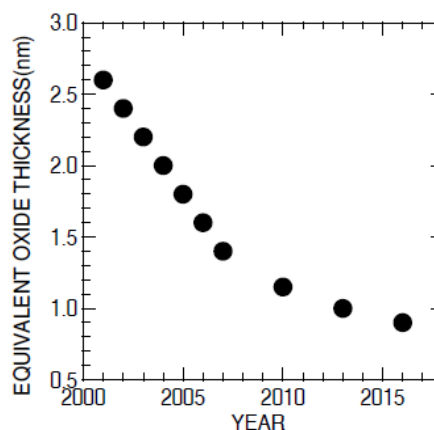


Fig. 1 Reduction of equivalent oxide thickness vs. year referred from the 2002 ITRS road map. This is an example.

but no blank lines between the paragraphs in each section. The section headings should be given by bold letters.

### Fonts

Font styles and sizes as specified in Table 1 are desirable.

### Figures and Tables

A blank line is to be placed between the text and the figures and tables. Large figures and tables may span both columns. Photographs should have a high contrast in black and white. Figure captions should be placed just below the corresponding figures and table captions above the tables.

### References

All the references are indicated in the main text by a number in square brackets on the line like this [1], and the full reference should be given in a numerical list at the end of the abstract. The reference style in accordance with the one found in Jpn. J. Appl. Phys. is recommended. Any technical queries on the typing may be e-mailed to the following address: [miyazaki@sxsys.hiroshima-u.ac.jp](mailto:miyazaki@sxsys.hiroshima-u.ac.jp)

### **3 Submitting the abstracts**

The author(s) is requested to check spelling and carefully proofread your abstracts. Sending PDF format abstract file and filling up the application form on the WEB site with following the guide.

The deadline for receipt of the abstracts will be announced on the IWDTF-11 web site soon.

### **4 Conference Proceedings**

The Conference Proceedings will be published as a special issue of Jpn. J. Appl. Phys. The authors are requested to prepare your manuscript as an original paper of JJAP. Your paper will be published after the usual reviewing process in JJAP. The detailed schedule will be announced on the IWDTF-11 web site soon.

### **Conclusions**

A model abstract for the Workshop has been given.

### **Acknowledgment**

The committee members concerned would like to express sincere thanks to all the contributors to the Workshop for their cooperation in the Workshop program.

### **References**

[1] Author(s): the usual abbreviated title of the journal, the volume number (year) the first page number.

[2] Author(s): Extended Abstracts of 2008 Intern. Workshop on Dielectric Thin Films for Future ULSI, Tokyo, 2006, p.1.